



# FFP08S60S Stealth 2 Rectifier

## Features

- High Speed Switching ( Max.  $t_{rr} < 30ns$  @  $I_F = 8A$  )
- High Reverse Voltage and High Reliability
- Avalanche Energy Rated

## Applications

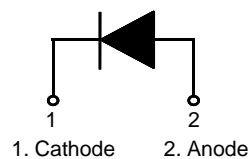
- General Purpose
- Switching Mode Power Supply
- Boost Diode in continuous mode power factor corrections
- Power switching circuits

## 8A, 600V Stealth2 Rectifier

The FFP08S60S is stealth 2 rectifier with soft recovery characteristics ( $t_{rr} < 30ns$ ). They has half the recovery time of hyperfast rectifier and are silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as freewheeling of boost diode in switching power supplies and other power swithching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

## Pin Assignments



## Absolute Maximum Ratings $T_C = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{RRM}$	Peak Repetitive Reverse Voltage	600	V
$V_{RWM}$	Working Peak Reverse Voltage	600	V
$V_R$	DC Blocking Voltage	600	V
$I_{F(AV)}$	Average Rectified Forward Current @ $T_C = 115^\circ C$	8	A
$I_{FSM}$	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	80	A
$T_J, T_{STG}$	Operating Junction and Storage Temperature	- 65 to +150	$^\circ C$

## Thermal Characteristics $T_C = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Max	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	2.5	$^\circ C/W$

## Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
F08S60S	FFP08S60STU	TO-220-2L	-	-	50

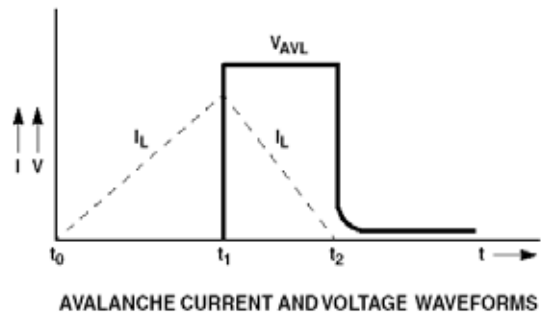
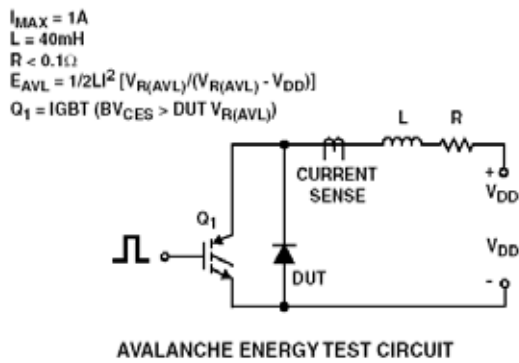
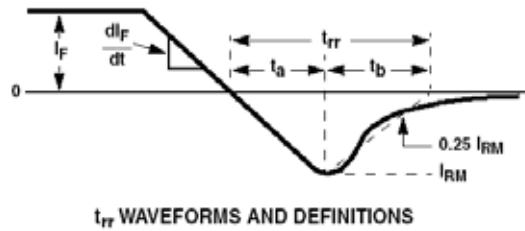
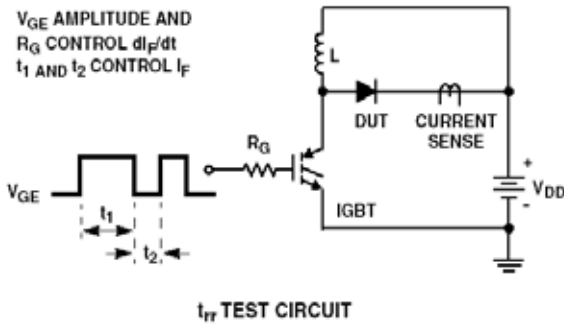
**Electrical Characteristics**  $T_C = 25^\circ\text{C}$  unless otherwise noted

Parameter	Conditions	Min.	Typ.	Max	Units	
$V_{FM}^1$	$I_F = 8\text{A}$	$T_C = 25^\circ\text{C}$	-	2.1	2.6	V
	$I_F = 8\text{A}$	$T_C = 125^\circ\text{C}$	-	1.6	-	V
$I_{RM}^1$	$V_R = 600\text{V}$	$T_C = 25^\circ\text{C}$	-	-	100	$\mu\text{A}$
	$V_R = 600\text{V}$	$T_C = 125^\circ\text{C}$	-	-	500	$\mu\text{A}$
$t_{rr}$	$I_F = 1\text{A}$ , $di/dt = 100\text{A}/\mu\text{s}$ , $V_R = 30\text{V}$	$T_C = 25^\circ\text{C}$	-	-	25	ns
$t_{rr}$	$I_F = 8\text{A}$ , $di/dt = 200\text{A}/\mu\text{s}$ , $V_R = 390\text{V}$	$T_C = 25^\circ\text{C}$	-	19	30	ns
$I_{rr}$			-	2.2	-	A
S factor			-	0.6	-	
$Q_{rr}$			-	21	-	nC
$t_{rr}$	$I_F = 8\text{A}$ , $di/dt = 200\text{A}/\mu\text{s}$ , $V_R = 390\text{V}$	$T_C = 125^\circ\text{C}$	-	58	-	ns
$I_{rr}$			-	4.3	-	A
S factor			-	1.3	-	
$Q_{rr}$			-	125	-	nC
$W_{AVL}$	Avalanche Energy ( $L = 40\text{mH}$ )	20	-	-	mJ	

**Notes:**

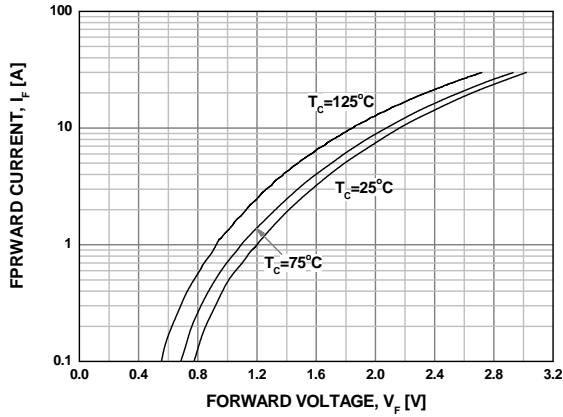
1. Pulse : Test Pulse width =  $300\mu\text{s}$ , Duty Cycle = 2%

**Test Circuit and Waveforms**

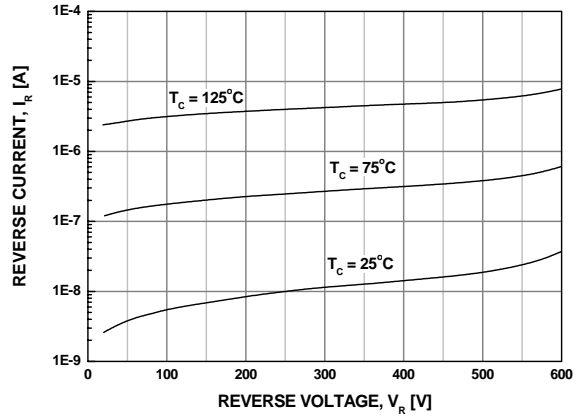


**Typical Performance Characteristics**  $T_c = 25^\circ\text{C}$  unless otherwise noted

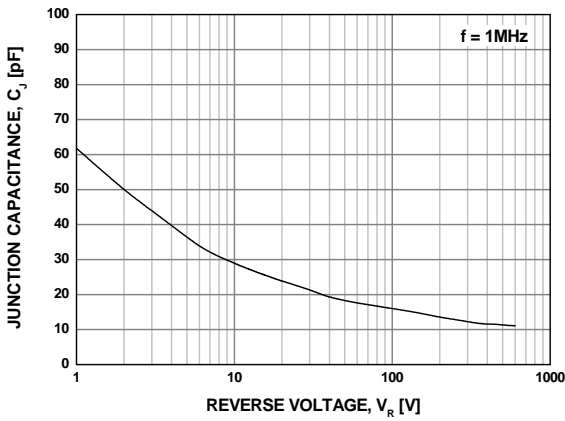
**Figure 1. Typical Forward Voltage Drop**



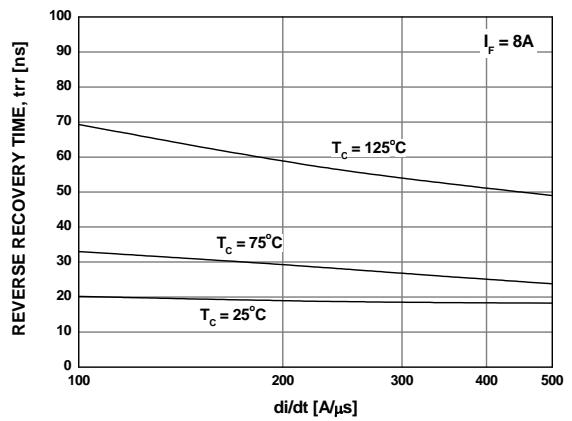
**Figure 2. Typical Reverse Current**



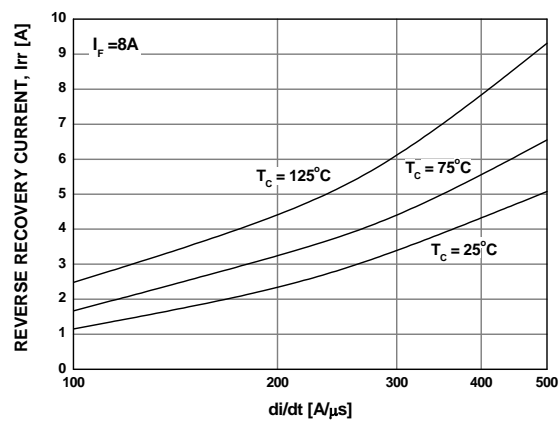
**Figure 3. Typical Junction Capacitance**



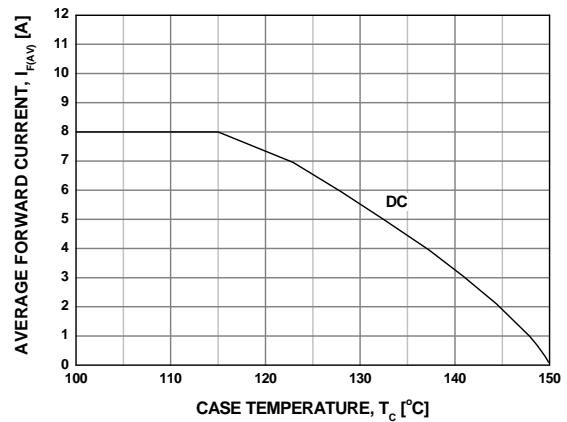
**Figure 4. Typical Reverse Recovery Time**



**Figure 5. Typical Reverse Recovery Current**

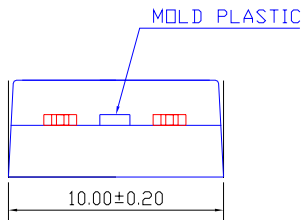
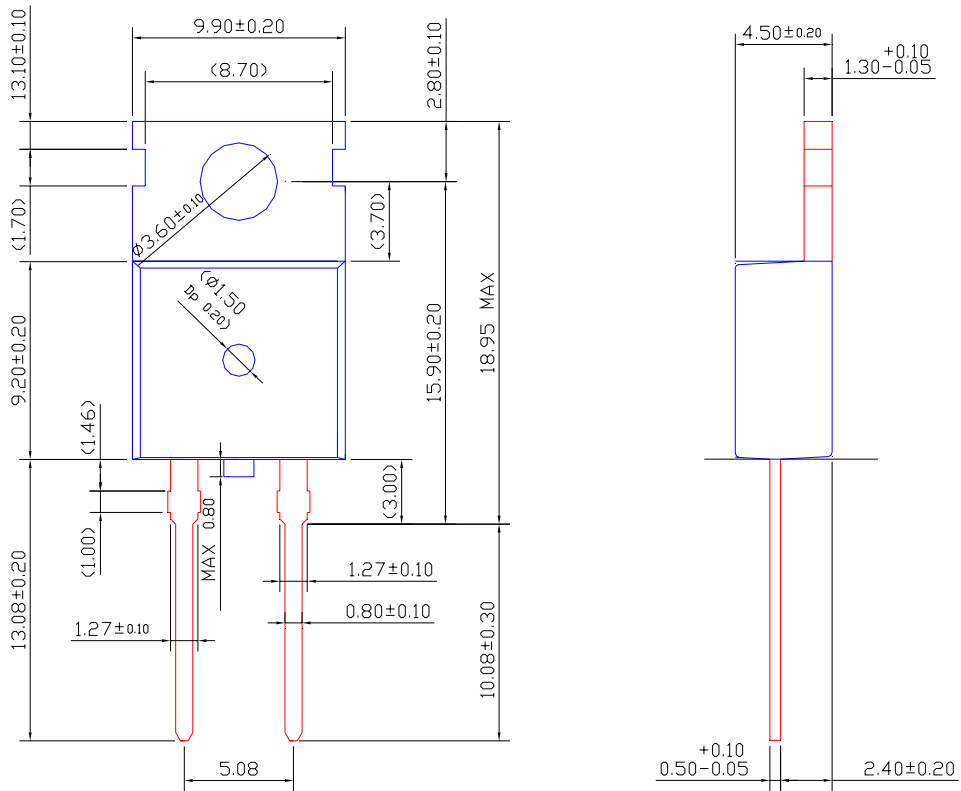


**Figure 6. Forward Current Deration Curve**



Mechanical Dimensions

TO-220-2L



NOTE


1. THESE DIMENSIONS DO NOT INCLUDE MOLD PROTRUSION.
2. ( ) IS REFERENCE
3. [ ] IS ASS'Y OUT QUALITY

Dimensions in Millimeters



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